

The documentation and process conversion measures necessary to comply with this revision shall be completed by 16 November 1998

INCH-POUND

MIL-PRF-19500/649A
 16 August 1998
 SUPERSEDING
 MIL-PRF-19500/649
 18 April 1997

PERFORMANCE SPECIFICATION

SEMICONDUCTOR DEVICE, DIODE, SILICON,
 POWER RECTIFIER, SCHOTTKY,
 TYPE 1N6781
 JAN, JANTX, JANTXV AND JANS

This specification is approved for use by all Departments and Agencies of the Department of Defense.

1. SCOPE

1.1 Scope. This specification covers the performance requirements for silicon, schottky, power rectifier diodes. Four levels of product assurance are provided for each device type as specified in MIL-PRF-19500.

1.2 Physical dimensions. See figure 1 (2 pin, isolated, TO-257).

1.3 Maximum ratings.

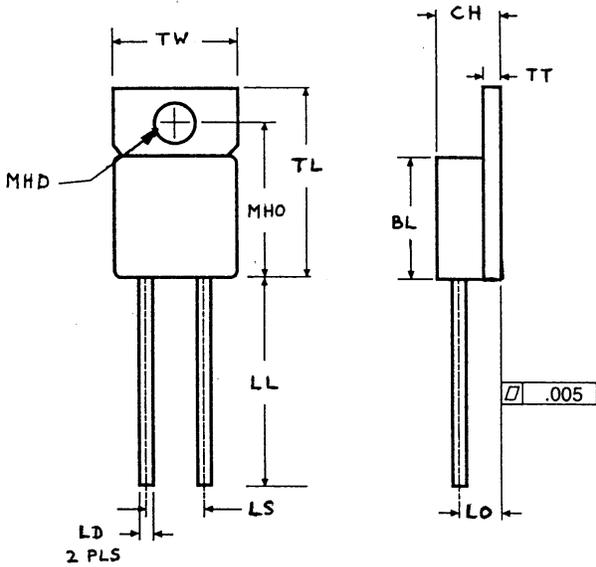
Type	$V_{RRM} = V_{RWM}$	I_o 1/ $T_J = T_C = 100^\circ\text{C}$	I_{FSM} $T_C = +100^\circ\text{C}$ $t_p = 8.3$ ms	$R_{\theta JC}$	$R_{\theta JA}$	T_{STG} and T_{OP}
	<u>V(pk)</u>	<u>A dc</u>	<u>A(pk)</u>	<u>°C/W</u>	<u>°C/W</u>	<u>°C</u>
1N6781	60	15	120	2.5	45	-65 to +150

1/ Derate at 300 mA/°C above $T_C = +100^\circ\text{C}$.

1.4 Primary electrical characteristics. Unless otherwise specified, primary electrical characteristics at $+25^\circ\text{C}$.

Type	V_{F1} $I_F = 5$ A dc	V_{F3} $I_F = 15$ A dc	I_{R1} $V_R = 0.8 V_{RWM}$ (See 1.3)	I_{R2} $V_R = 0.8 V_{RWM}$ (See 1.3) $T_C = +125^\circ\text{C}$	C_J $V_R = 5$ V $f = 1$ MHz
	<u>V dc</u>	<u>V dc</u>	<u>mA dc</u>	<u>mA dc</u>	<u>pF</u>
1N6781	0.70	0.88	0.30	300	900

Beneficial comments (recommendations, additions, deletions) and any pertinent data which may be of use in improving this document should be addressed to: Commander, Defense Supply Center, Columbus, ATTN: DSCC-VA, 3990 East Broad Street, Columbus, Ohio 43216-5000, by using the Standardization Document Improvement Proposal (DD Form 1426) appearing at the end of this document or by letter.



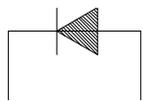
Dimensions				
Symbol	Inches		Millimeters	
	Min	Max	Min	Max
BL	.410	.430	10.4	10.9
CH	.249	.260	6.32	6.60
LD	.035	.045	0.89	1.14
LL	.500	.750	12.70	19.05
LO	.150 typ		3.81 typ	
LS	.200 bsc		5.08 bsc	
MHD	.140	.150	3.55	3.80
MHO	.527	.537	13.4	13.6
TL	.645	.665	16.4	16.9
TT	.040	.050	1.02	1.27
TW	.410	.420	10.4	10.7

NOTES:

1. Dimensions are in inches.
2. Metric equivalents are given for general information only. See 3.3.
3. All terminals are isolated from case.

Configuration

Terminal	Description
1	Cathode
2	Anode



1 2

FIGURE 1. Physical dimensions and configuration (2 pin, isolated, similar to TO-257).

2. APPLICABLE DOCUMENTS

2.1 General. The documents listed in this section are specified in sections 3 and 4 of this specification. This section does not include documents cited in other sections of this specification or recommended for additional information or as examples. While every effort has been made to ensure the completeness of this list, document users are cautioned that they must meet all specified requirements documents cited in sections 3 and 4 of this specification, whether or not they are listed.

2.2 Government documents.

2.2.1 Specifications, standards, and handbooks. The following specifications, standards, and handbooks form a part of this document to the extent specified herein. Unless otherwise specified, the issues of these documents are those listed in the issue of the Department of Defense Index of Specifications and Standards (DODISS) and supplement thereto, cited in the solicitation (see 6.2).

SPECIFICATION

DEPARTMENT OF DEFENSE

MIL-PRF-19500 - Semiconductor Devices, General Specification for.

STANDARD

MILITARY

MIL-STD-750 - Test Methods for Semiconductor Devices.

(Unless otherwise indicated, copies of federal and military specifications, standards, and handbooks are available from the Standardization Documents Order Desk, Building 4D, 700 Robbins Avenue, Philadelphia, PA 19111-5094.)

2.3 Order of precedence. In the event of a conflict between the text of this document and the references cited herein (except for related associated specifications or specification sheets), the text of this document takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 Associated specification. The individual item requirements shall be in accordance with MIL-PRF-19500 and as specified herein.

3.2 Abbreviations, symbols, and definitions. Abbreviations, symbols, and definitions used herein shall be as specified in MIL-PRF-19500.

3.3 Interface requirements and physical dimensions. The interface requirements and physical dimensions shall be as specified in MIL-PRF-19500 and on figure 1 (similar to TO-257) herein. Methods used for electrical isolation of the terminal feedthroughs shall employ materials that contain a minimum of 90 percent Al_2O_3 (ceramic). Examples of such construction techniques are metallized ceramic eyelets or ceramic walled packages. The preferred measurements used herein is the metric SI system. However, since this item was originally designed using inch-pound units of measurement, in the event of a conflict between the metric and inch-pound units, the inch-pound units shall take precedence.

3.3.1 Lead material and finish. Lead finish shall be solderable as defined in MIL-PRF-19500, MIL-STD-750, and herein. Where a choice of lead finish or formation is desired, it shall be specified in the acquisition document (see 6.2). When lead formation is performed, as a minimum, the vendor shall perform 100 percent hermetic seal in accordance with screen 14 of table II of MIL-PRF-19500 and 100 percent DC testing in accordance with Group A, subgroup 2 herein.

3.3.2 Polarity. Polarity and terminal configuration shall be in accordance with figure 1 herein.

3.4 Marking. Marking shall be in accordance with MIL-PRF-19500.

3.5 Electrical performance characteristics. Unless otherwise specified herein, the electrical performance characteristics are as specified in 1.3, 1.4, and table I herein.

3.6 Electrical test requirements. The electrical test requirements shall be the subgroups specified in 4.4.2 and 4.4.3 herein.

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3.7 Qualification. Devices furnished under this specification shall be products that are authorized by the qualifying activity for listing on the applicable qualified products list before contract award (see 4.2 and 6.2).

4. VERIFICATION

4.1 Classification of Inspections. The inspection requirements specified herein are classified as follows:

- a. Qualification inspection (see 4.2).
- b. Screening (see 4.3)
- c. Conformance inspection (see 4.4).

4.2 Qualification inspection. Qualification inspection shall be in accordance with MIL-PRF-19500, and table III and 4.3.3 herein.

4.3 Screening (JANS, JANTX, and JANTXV levels). Screening shall be in accordance with table IV of MIL-PRF-19500, and as specified herein. The following measurements shall be made in accordance with table I herein. Devices that exceed the limits of table I herein shall not be acceptable.

Screen (see table IV of MIL-PRF-19500)	Measurement	
	JANS level	JANTX and JANTXV levels
3C 1/	Thermal impedance (see 4.3.2)	Thermal impedance (see 4.3.2)
9 and 10	Not applicable	Not applicable
11	I_{R1} and V_{F2}	I_{R1} and V_{F2}
12	See 4.3.1, $t = 240$ hours	See 4.3.1, $t = 48$ hours
13	Subgroups 2 and 3 of table I herein; I_{R1} and V_{F2} ; $\Delta I_{R1} \leq 100$ percent of initial value or $\pm 75 \mu A$, whichever is greater; $\Delta V_{F2} \leq \pm 50$ mV.	Subgroup 2 of table I herein; I_{R1} and V_{F2} ; $\Delta I_{R1} \leq 100$ percent of initial value or $\pm 75 \mu A$, whichever is greater; $\Delta V_{F2} \leq \pm 50$ mV.

1/ Thermal impedance shall be performed any time before screen 13.

4.3.1 Power burn-in conditions. Power burn-in conditions are as follows:

MIL-STD-750 method 1038, test condition A. $T_C = +125^\circ C$; $V_R = 48$ V dc.

4.3.2 Thermal impedance ($Z_{\theta JX}$) measurements for screening. The $Z_{\theta JX}$ measurements shall be performed in accordance with MIL-STD-750, method 3101. The maximum limit (not to exceed the group A, subgroup 2 limit) and conditions for $Z_{\theta JX}$ in screening (table IV of MIL-PRF-19500) shall be derived by each vendor by means of statistical process control. When the process has exhibited control and capability, the capability data shall be used to establish the fixed screening limit. In addition to screening, once a fixed limit has been established, monitor all future sealing lots using a random five piece sample from each lot to be plotted on the applicable X, R chart. If a lot exhibits an out of control condition, the entire lot shall be removed from the line and held for Engineering evaluation and disposition.

4.3.2.1 Thermal impedance ($Z_{\theta JX}$) measurements for initial qualification or requalification. The $Z_{\theta JX}$ measurements shall be performed in accordance with MIL-STD-750, method 3101 (read and record data $Z_{\theta JX}$) derived conditions limits and thermal response curve shall be supplied to the qualifying activity on the qualification lot prior to qualification approval.

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4.4 Conformance inspection. Conformance inspection shall be in accordance with MIL-PRF-19500 and as specified herein.

4.4.1 Group A inspection. Group A inspection shall be conducted in accordance with MIL-PRF-19500 and table I herein. Electrical measurements (end-points) and delta requirements shall be in accordance with the applicable steps of table II herein. The following test conditions shall be used for $Z_{\theta JX}$, group A inspection:

- a. I_M measure current ----- 15 mA
- b. I_H forward heating current ----- 9.9 A
- c. t_H heating time ----- 200 ms
- d. t_{MD} measurement delay time ----- 35 μ s
- e. V_H heating voltage ----- 1 V

The maximum limit for $Z_{\theta JX}$ under these conditions are $Z_{\theta JX}(max) = 2.4^\circ C/W$

4.4.2 Group B inspection. Group B inspection shall be conducted in accordance with the conditions specified for subgroup testing in table VIa (JANS) and table VIb (JANTX and JANTXV) of MIL-PRF-19500 and as follows. Electrical measurements (end-points) and delta requirements shall be in accordance with the applicable steps of table II herein.

4.4.2.1 Group B inspection, table VIa (JANS) of MIL-PRF-19500.

<u>Subgroup</u>	<u>Method</u>	<u>Condition</u>
4	1037	I_F or $I_O = 2$ A (minimum); $\Delta T_J = +85^\circ C$, minimum for 2,000 cycles minimum.
5	1038	Condition A, $T_J = T_C = +150^\circ C$, $V_R = 48$ V dc.
6	3101	Limit for thermal resistance is $R_{\theta JC} = 2.5^\circ C/W$.

4.4.2.2 Group B inspection, table VIb (JANTX and JANTXV) of MIL-PRF-19500.

<u>Subgroup</u>	<u>Method</u>	<u>Condition</u>
3	1037	I_F or $I_O = 2$ A (minimum); $\Delta T_J = +85^\circ C$, minimum for 2,000 cycles minimum.

4.4.3 Group C inspection. Group C inspection shall be conducted in accordance with the conditions specified for subgroup testing in table VII of MIL-PRF-19500 and as follows. Electrical measurements (end-points) and delta requirements shall be in accordance with the applicable steps of table II herein.

4.4.3.1 Group C inspection, table VII of MIL-PRF-19500.

<u>Subgroup</u>	<u>Method</u>	<u>Condition</u>
2	2036	Test condition A, 5 pounds, $t = 15$ seconds ± 3 seconds.
3	2006	X1, Y1, Z1 and Z2 axis.
6	1037	I_F or $I_O = 2$ A (minimum); $\Delta T_J = +85^\circ C$, minimum for 6,000 cycles minimum.

4.4.4 Group E inspection. Group E inspection shall be conducted in accordance with the conditions specified for subgroup testing in table III herein. Electrical measurements (end points) and delta requirements shall be in accordance with the applicable steps and footnotes of table II herein.

4.5 Methods of inspection. Methods of inspection shall be as specified in the appropriate tables and as follows.

4.5.1 Pulse measurements. Conditions for pulse measurement shall be as specified in section 4 of MIL-STD-750.

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TABLE I. Group A inspection. 1/

Inspection	MIL-STD-750		Symbol	Limits		Unit
	Method	Conditions		Min	Max	
<u>Subgroup 1</u> Visual and mechanical examination	2071					
<u>Subgroup 2</u> Thermal impedance 2/ Forward voltage	3101 4011	See 4.4.1 Pulsed 3/ I _F = 5 A dc I _F = 10 A dc I _F = 15 A dc	Z _{θJX} V _{F1} V _{F2} V _{F3}		2.40 0.70 0.81 0.88	°C/W V dc V dc V dc
Reverse leakage current	4016	DC method; pulsed 3/ V _R = 48 V (pk)	I _{R1}		0.30	mA dc
<u>Subgroup 3</u> High temperature operation: Reverse leakage current	4016	T _A = +125°C DC method; pulsed 3/ V _R = 48 V (pk)	I _{R2}		300	mA dc
Low-temperature operation: Forward voltage	4011	T _A = -55°C Pulsed 3/ I _F = 15 A dc	V _{F4}		0.98	V dc
<u>Subgroup 4</u> Junction capacitance	4001	V _R = 5 V dc; f = 1.0 MHz	C _J		900	pF
<u>Subgroups 5 and 7</u> Not applicable						
<u>Subgroup 6</u> Surge current	4066	Condition A1; T _A = +25°C, I _{FSM} = 120 A(pk), V _{RM} = 60 V(pk), I _O = 0 A(pk), 6 surges of 8.3 ms each at 1 minute intervals				
Electrical measurements		See table II herein, steps 1 and 2				

1/ For sampling plans not specified, see MIL-PRF-19500.

2/ If 4.4.1 test conditions are performed in 100 percent screening, this test need not be performed in group A.

3/ Pulse test: Pulse width = 300 μs, duty cycle ≤ 2 percent.

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TABLE II. Groups A, B, C, and E electrical measurements. 1/ 2/ 3/

Step	Inspection	MIL-STD-750		Symbol	Limits		Unit
		Method	Conditions		Min	Max	
1	Forward voltage	4011	$I_F = 10$ A dc pulsed	V_{F2}		0.81	V dc
2	Reverse leakage current	4016	$V_R = 48$ V dc pulsed DC method	I_{R1}		0.30	mA dc
3	Forward voltage	4011	$I_F = 10$ A dc pulsed	ΔV_{F2}		±50 mV dc from initial reading	
4	Reverse leakage current	4016	$V_R = 48$ V dc pulsed DC method	ΔI_{R1}		100 percent of initial value or ±75 µA dc whichever is greater.	
5	Thermal impedance	3101	See 4.4.1	$Z_{\theta JX}$		2.40	°C/W

1/ The electrical measurements for table VIa (JANS) of MIL-PRF-19500 are as follows:

- a. Subgroup 3, see table II herein, steps 1 and 2.
- b. Subgroup 4, see table II herein, steps 1, 2, 3, 4, and 5.
- c. Subgroup 5, see table II herein, steps 1, 2, 3, and 4.

2/ The electrical measurements for table VIb (JANTX and JANTXV) of MIL-PRF-19500 are as follows:

- a. Subgroup 2, see table II herein, steps 1 and 2.
- a. Subgroup 3, see table II herein, steps 1, 2, and 5.
- a. Subgroup 6, see table II herein, steps 1 and 2.

3/ The electrical measurements for table VII of MIL-PRF-19500 are as follows:

- a. Subgroups 2 and 3, see table II herein, steps 1 and 2 for all levels.
- a. Subgroup 6, see table II herein, steps 1, 2, and 5 for all levels.

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TABLE III. Group E inspection (all quality levels) for qualification only. ^{1/}

Inspection	MIL-STD-750		Sampling plan
	Method	Conditions	
<u>Subgroup 1</u>			22 devices c = 0
Thermal shock (temperature cycling)	1051	500 cycles	
Hermetic seal	1071		
Fine leak		Test condition H 5×10^{-7} atm cc/s	
Gross leak		Test condition C or K	
Electrical measurements		See table II herein, steps 1 and 2	
<u>Subgroup 2</u>			22 devices c = 0
Steady-state blocking life	1048	t = 1,000 hours, T _C = +125°C V _R = 48 V dc	
Electrical measurements		See table II herein, steps 1 and 2	
<u>Subgroup 3</u>			3 devices c = 0
Destructive physical analysis	2101		
<u>Subgroup 4</u>			22 devices c = 0
Thermal resistance	3101	See 4.5.2; R _{θJC} = 2.5°C/W	
<u>Subgroup 5</u>			
Not applicable			

^{1/} For initial design and process change verification only (one time testing).

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4.5.2 Thermal resistance. Thermal resistance measurements shall be performed in accordance with method 3101 of MIL-STD-750. The maximum limits for $R_{\theta JC}$ (max) shall be 2.5°C/W for devices in the 2 pin case style. The following parameter measurements shall apply:

- a. I_M measure current ----- 15 mA
- b. I_H forward heating current ----- 9.9 A
- c. t_H heating time ----- Steady state (see MIL-STD-750, method 3101)
- d. t_{MD} measurement delay time ----- 35 μ s
- e. V_H heating voltage ----- 1 V

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging must be in accordance with MIL-PRF-19500.

5.2 Marking. Unless otherwise specified (see 6.2), marking shall be in accordance with MIL-STD-129.

6. NOTES

(This section contains information of a general or explanatory nature that may be helpful, but is not mandatory.)

6.1 Notes. The notes specified in MIL-PRF-19500 are applicable to this specification.

6.2 Acquisition requirements. Acquisition documents should specify the following:

- a. Lead finish (see 3.3.1).
- b. Type designation and product assurance level.
- c. Packaging requirements (see 5.1).

6.3 Cross reference list. Parts covered by this specification may be used to replace the following commercial Part of Identifying Numbers (PIN):

Preferred types	Commercial types
JAN1N6781, JANTX1N6781, JANTXV1N6781, JANS1N6781	1N6781

6.4 Qualification. With respect to products requiring qualification, awards will be made only for products which are, at the time of award of contract, qualified for inclusion in Qualified Products List QPL-19500 whether or not such products have actually been so listed by that date. The attention of the contractors is called to these requirements, and manufacturers are urged to arrange to have the products that they propose to offer to the Federal Government tested for qualification in order that they may be eligible to be awarded contracts or purchase orders for the products covered by this specification. Information pertaining to qualification of products may be obtained from Defense Supply Center Columbus, DSCC-VQE, Columbus, OH 43216.

6.5 Changes from previous issue. Marginal notations are not used in this revision to identify changes with respect to the previous issue due to the extent of the changes.

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Custodians:
Army - CR
Navy - EC
Air Force - 17
NASA - NA
DLA - CC

Preparing activity:
DLA - CC

(Project 5961-1990)

STANDARDIZATION DOCUMENT IMPROVEMENT PROPOSAL

INSTRUCTIONS

1. The preparing activity must complete blocks 1, 2, 3, and 8. In block 1, both the document number and revision letter should be given.
2. The submitter of this form must complete blocks 4, 5, 6, and 7.
3. The preparing activity must provide a reply within 30 days from receipt of the form.

NOTE: This form may not be used to request copies of documents, nor to request waivers, or clarification of requirements on current contracts. Comments submitted on this form do not constitute or imply authorization to waive any portion of the referenced document(s) or to amend contractual requirements.

I RECOMMEND A CHANGE:	1. DOCUMENT NUMBER MIL-PRF-19500/649A	2. DOCUMENT DATE 16 August 1998
3. DOCUMENT TITLE SEMICONDUCTOR DEVICE, DIODE, SILICON, POWER RECTIFIER, SCHOTTKY, TYPE 1N6781, JAN, JANTX, JANTXV, AND JANS		
5. REASON FOR RECOMMENDATION		
6. SUBMITTER		
a. NAME (Last, First, Middle initial)	b. ORGANIZATION	
c. ADDRESS (Include Zip Code)	d. TELEPHONE (Include Area Code) Commercial DSN FAX EMAIL	7. DATE SUBMITTED
8. PREPARING ACTIVITY		
a. Point of Contact Alan Barone	b. TELEPHONE Commercial DSN FAX EMAIL 614-692-0510 850-0510 614-692-6939 alan_barone@dsc.dla.mil	
c. ADDRESS Defense Supply Center Columbus ATTN: DSCC-VAT Columbus, OH 43216-5000	IF YOU DO NOT RECEIVE A REPLY WITHIN 45 DAYS, CONTACT: Defense Quality and Standardization Office 5203 Leesburg Pike, Suite 1403, Falls Church, VA 22041-3466 Telephone (703) 756-2340 DSN 289-2340	